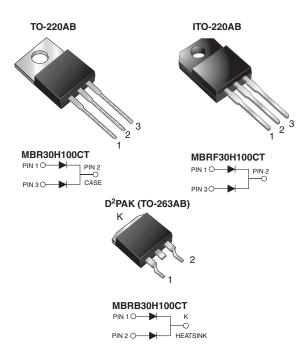
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# **Dual Common Cathode High Voltage Schottky Rectifier**

High Barrier Technology for Improved High Temperature Performance



### **DESIGN SUPPORT TOOLS**

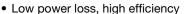
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PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	2 x 15 A					
$V_{RRM}$	100 V					
I <sub>FSM</sub>	275 A					
$V_{F}$	0.67 V					
I <sub>R</sub>	5.0 μΑ					
T <sub>J</sub> max.	175 °C					
Package	TO-220AC, ITO-220AC, D <sup>2</sup> PAK (TO-263AB)					
Circuit configuration	Dual common cathode					

### **FEATURES**

- Power pack
- · Guardring for overvoltage protection



- Low forward voltage drop
- · Low leakage current
- · High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

### **MECHANICAL DATA**

Case: TO-220AB, ITO-220AB, D2PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>C</sub> = 25 °C unless otherwise noted)						
PARAMETER			MBR30H100CT	UNIT		
Maximum repetitive peak reverse voltage			100			
Working peak reverse voltage			100	V		
Maximum DC blocking voltage			100			
Maximum average forward rectified current	total device		30	-		
(fig.1)	per diode	I <sub>F(AV)</sub>	15			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode			275	Α		
Peak repetitive reverse surge current per diode at $t_p = 2.0 \ \mu s$ , 1 kHz			1.0			
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000	V/µs		
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-65 to +175	°C		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		$V_{AC}$	1500	V		



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUE	UNIT	
Maximum instantaneous forward voltage per diode	V <sub>F</sub> (1)	I <sub>F</sub> = 15 A	T <sub>J</sub> = 25 °C	0.82	- - V	
		I <sub>F</sub> = 15 A	T <sub>J</sub> = 125 °C	0.67		
		I <sub>F</sub> = 30 A	T <sub>J</sub> = 25 °C	0.93		
		I <sub>F</sub> = 30 A	T <sub>J</sub> = 125 °C	0.80		
Maximum reverse current per diode	I <sub>R</sub> <sup>(2)</sup>	Rated V <sub>R</sub>	T <sub>J</sub> = 25 °C	5.0	μΑ	
			T <sub>J</sub> = 125 °C	6.0	mA	

#### Note

 $^{(1)}$  Pulse test: 300  $\mu$ s pulse width, 1 % duty cycle

 $^{(2)}$  Pulse test: Pulse width,  $\leq$  40 ms

THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Typical thermal resistance per diode	$R_{\theta JC}$	1.9	4.6	1.9	°C/W

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR30H100CT-E3/45	1.85	45	50/tube	Tube		
ITO-220AB	MBRF30H100CT-E3/45	1.99	45	50/tube	Tube		
TO-263AB	MBRB30H100CT-E3/45	1.35	45	50/tube	Tube		
TO-263AB	MBRB30H100CT-E3/81	1.35	81	800/reel	Tape and reel		

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## **RATINGS AND CHARACTERISTICS CURVES** (T<sub>C</sub> = 25 °C unless otherwise noted)

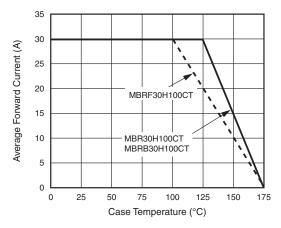


Fig. 1 - Forward Derating Curve Per Diode

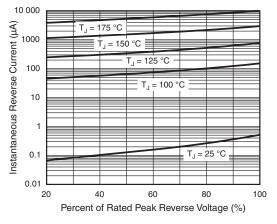


Fig. 4 - Typical Reverse Characteristics Per Diode

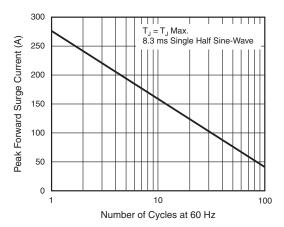


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

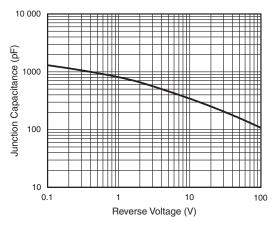


Fig. 5 - Typical Junction Capacitance Per Diode

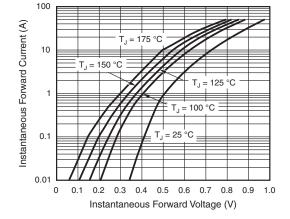


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

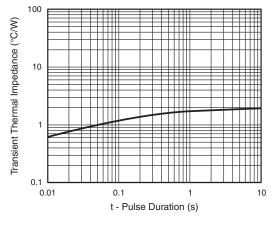
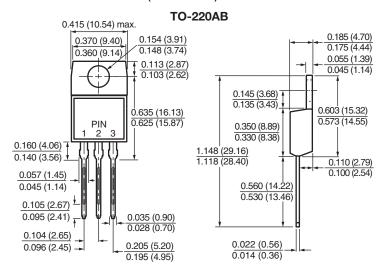


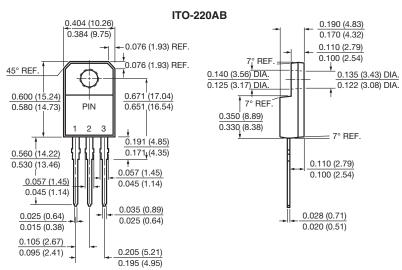
Fig. 6 - Typical Transient Thermal Impedance Per Diode



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## **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

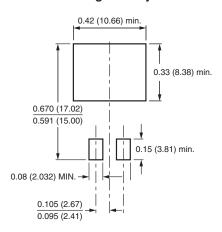




## D<sup>2</sup>PAK (TO-263AB)

#### 0.411 (10.45) 0.190 (4.83) 0.380 (9.65) 0.160 (4.06) 0.055 (1.40) 0.245 (6.22) 0.045 (1.14) MIN. 0.055 (1.40) 0.360 (9.14) 0.047 (1.19) 0.320 (8.13) 0.624 (15.85) Κ 2 0.591 (15.00) - 0 to 0.01 (0 to 0.254) 0.110 (2.79) 0.037 (0.940) 0.021 (0.53) 0.027 (0.686) 0.014 (0.36) 0.105 (2.67) 0.140 (3.56) 0.095 (2.41) 0.205 (5.20) 0.110 (2.79) 0.195 (4.95)

## **Mounting Pad Layout**





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